



IPAD™

EMIF06-10006F1

6 LINES EMI FILTER AND ESD PROTECTION

MAIN PRODUCT CHARACTERISTICS

Where EMI filtering in ESD sensitive equipment is required:

- Mobile phones and communication systems
- Computers, printers and MCU Boards

DESCRIPTION

The EMIF06-10006F1 is a highly integrated devices designed to suppress EMI/RFI noise in all systems subjected to electromagnetic interferences. The EMIF04 flip-chip packaging means the package size is equal to the die size.

This filter includes an ESD protection circuitry which prevents the device from destruction when subjected to ESD surges up 15kV. This device includes four EMIF filters and 4 separated ESD diodes.

BENEFITS

- EMI symmetrical (I/O) low-pass filter
- High efficiency in EMI filtering
- Very low PCB space consuming:
2.92mm x 1.29mm
- Very thin package: 0.65 mm
- High efficiency in ESD suppression
(IEC61000-4-2 level 4)
- High reliability offered by monolithic integration
- High reducing of parasitic elements through integration and wafer level packaging.

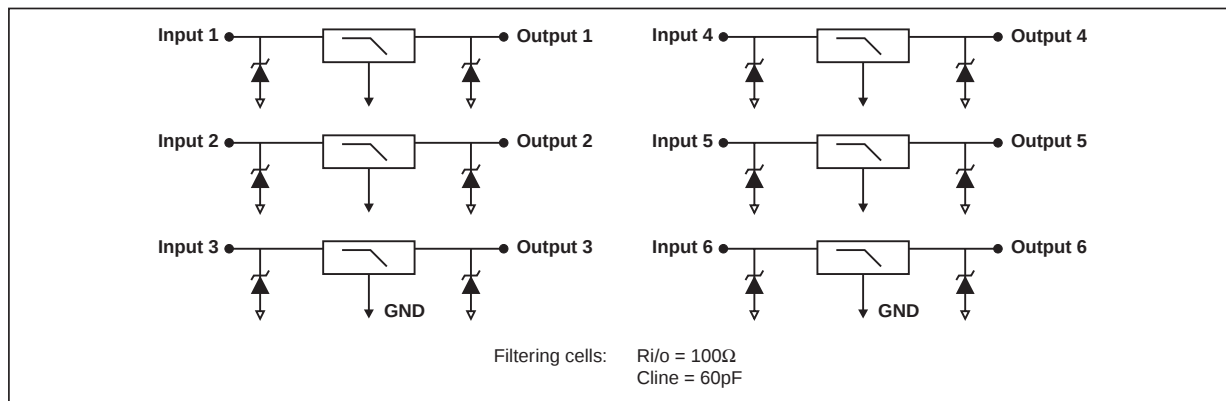
COMPLIES WITH THE FOLLOWING STANDARDS :

IEC 61000-4-2 level 4:

15kV (air discharge)
8 kV (contact discharge)

MIL STD 883E - Method 3015-6 Class 3

BASIC CELL CONFIGURATION



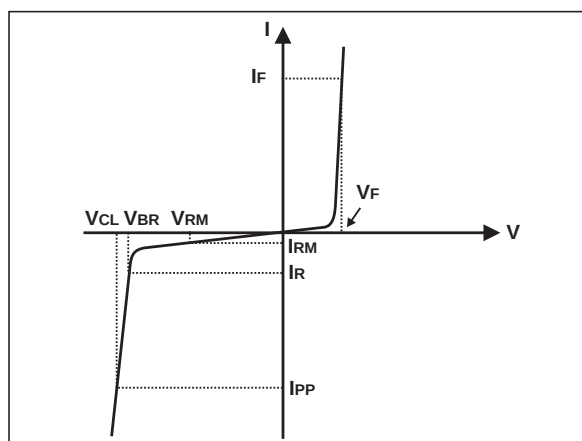
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ABSOLUTE RATINGS (limiting values)

Symbol	Parameter and test conditions	Value	Unit
P_R	DC power per resistance	0.1	W
P_T	Total DC power per package	0.6	W
T_j	Maximum junction temperature	125	°C
T_{op}	Operating temperature range	-40 to + 85	°C
T_{stg}	Storage temperature range	125	°C

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ °C}$)

Symbol	Parameter
V_{BR}	Breakdown voltage
I_{RM}	Leakage current @ V_{RM}
V_{RM}	Stand-off voltage
V_{CL}	Clamping voltage
R_d	Dynamic impedance
I_{PP}	Peak pulse current
$R_{I/O}$	Series resistance between Input and Output
C_{line}	Input capacitance per line



Symbol	Test conditions	Min.	Typ.	Max.	Unit
V_{BR}	$I_R = 1\text{ mA}$	5.5	7	9	V
I_{RM}	$V_{RM} = 3.3\text{ V per line}$			500	nA
$R_{I/O}$	$I = 10\text{ mA}$	80	100	120	Ω
C_{line}	$V_R = 2.5\text{ V}$, $F = 1\text{ MHz}$, 30 mV (on filter cells)	50	60	70	pF

Fig. 1: S21 (dB) attenuation measurements and Aplac simulation.

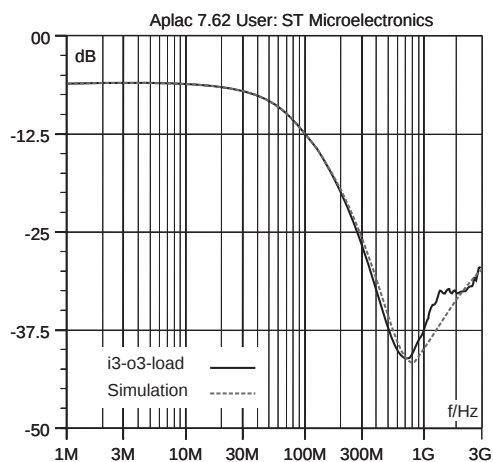


Fig. 3: Digital crosstalk measurements.

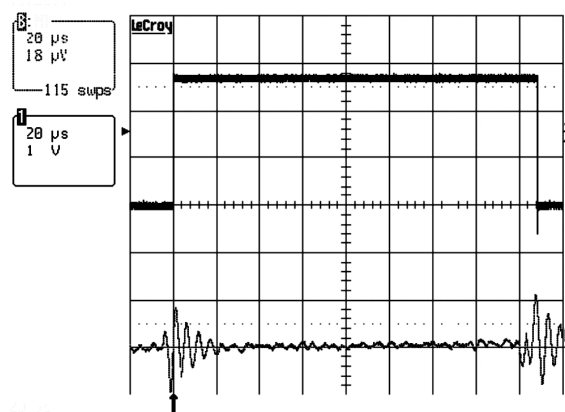


Fig. 5: ESD response to IEC61000-4-2 (-15kV air discharge) on one input V(in) and one output V(out).

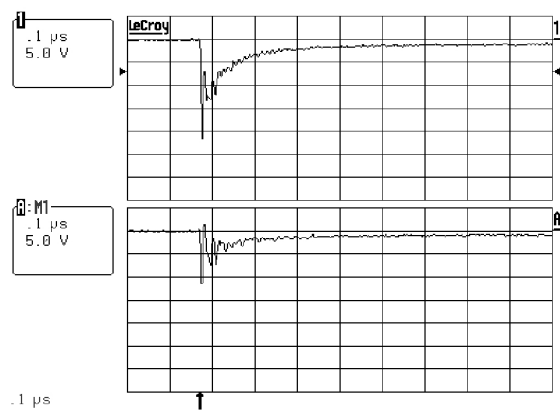


Fig. 2: Analog crosstalk measurements.

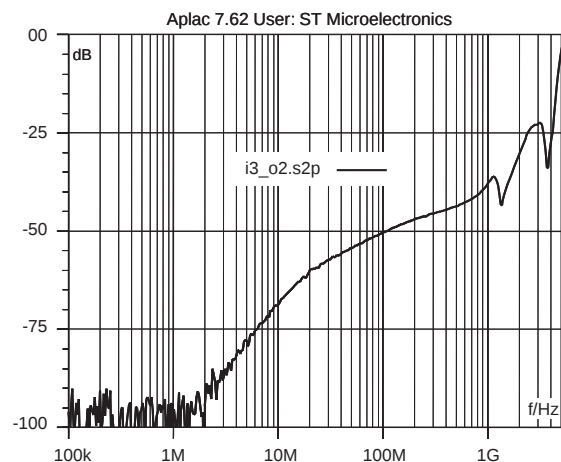


Fig. 4: ESD response to IEC61000-4-2 (+15kV air discharge) on one input V(in) and one output V(out).

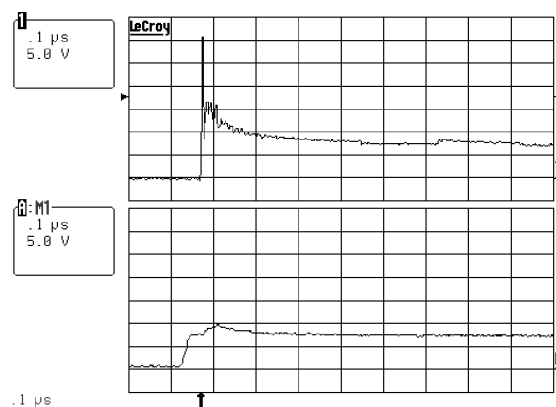
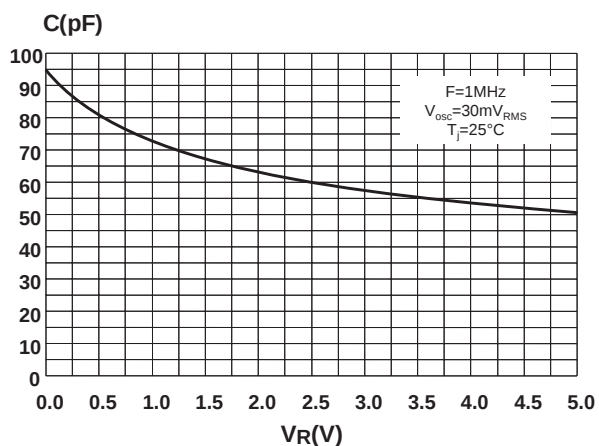
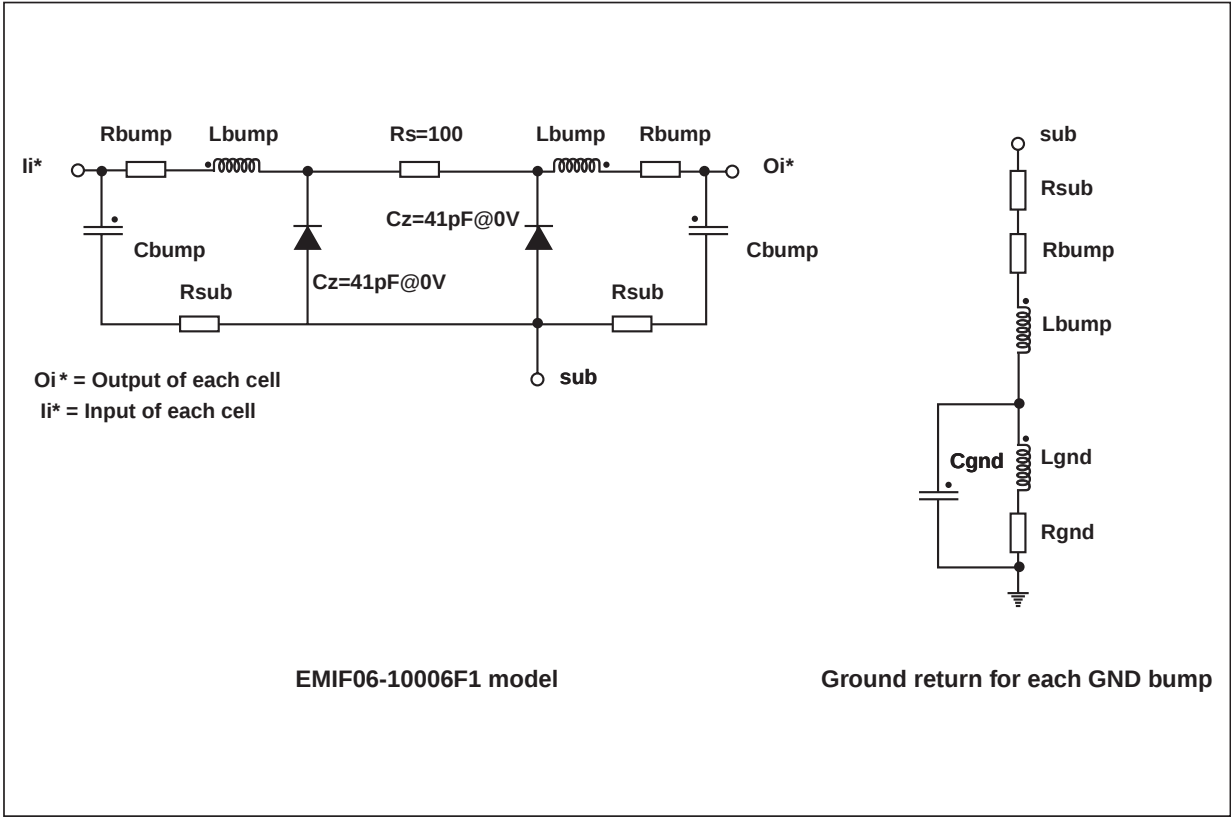


Fig. 6: Line capacitance versus applied voltage for filter.



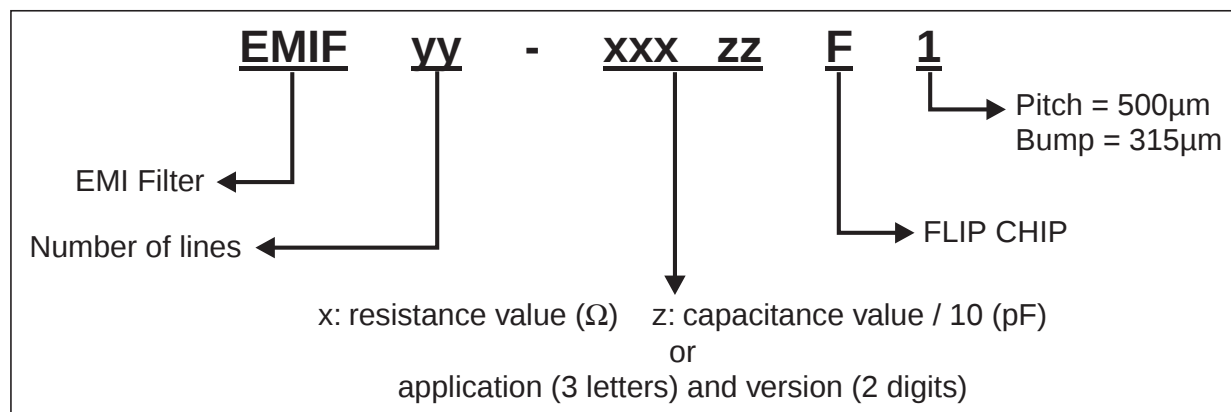
Aplac model



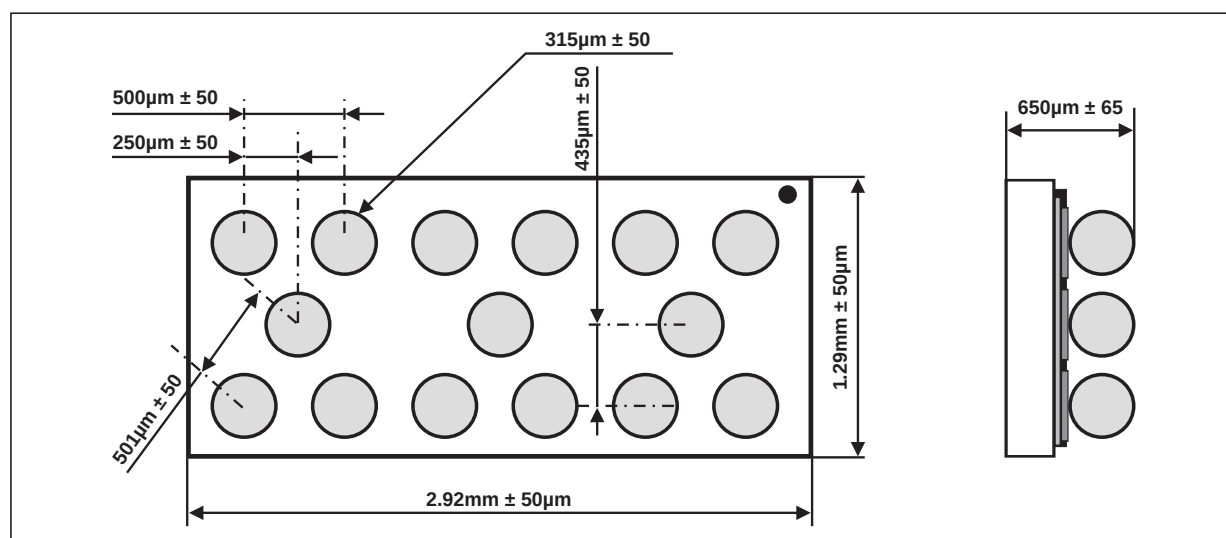
Aplac parameters

aplacvar R_s	100 Ω
aplacvar C_z	41 pF
aplacvar L_{bump}	50 pH
aplacvar R_{bump}	20 m
aplacvar C_{bump}	1.2 pF
aplacvar R_{sub}	100 m
aplacvar R_{gnd}	100 m
aplacvar L_{gnd}	100 pH
aplacvar C_{gnd}	0.15 pF

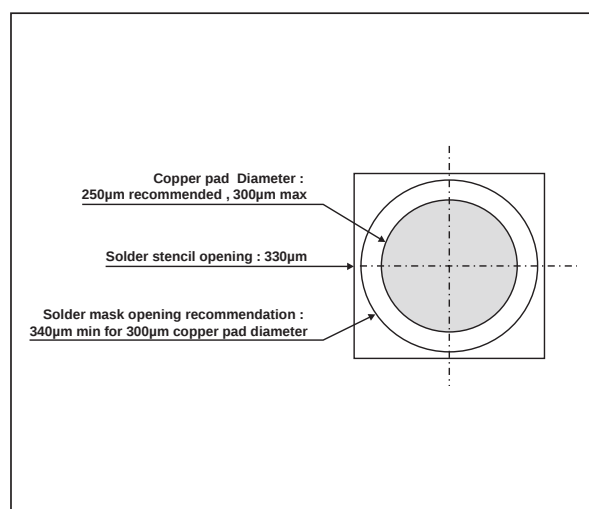
ORDER CODE



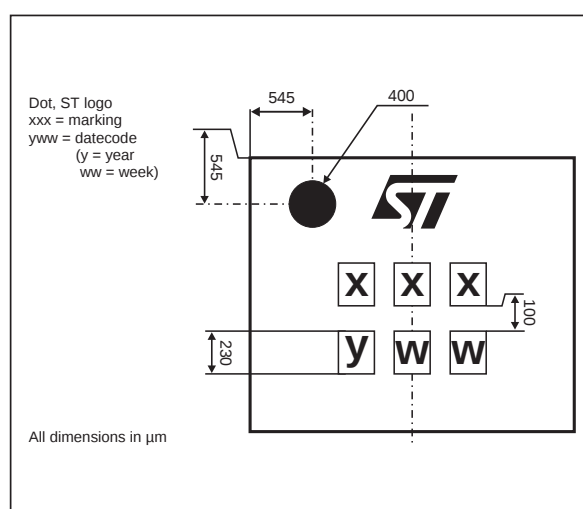
PACKAGE MECHANICAL DATA



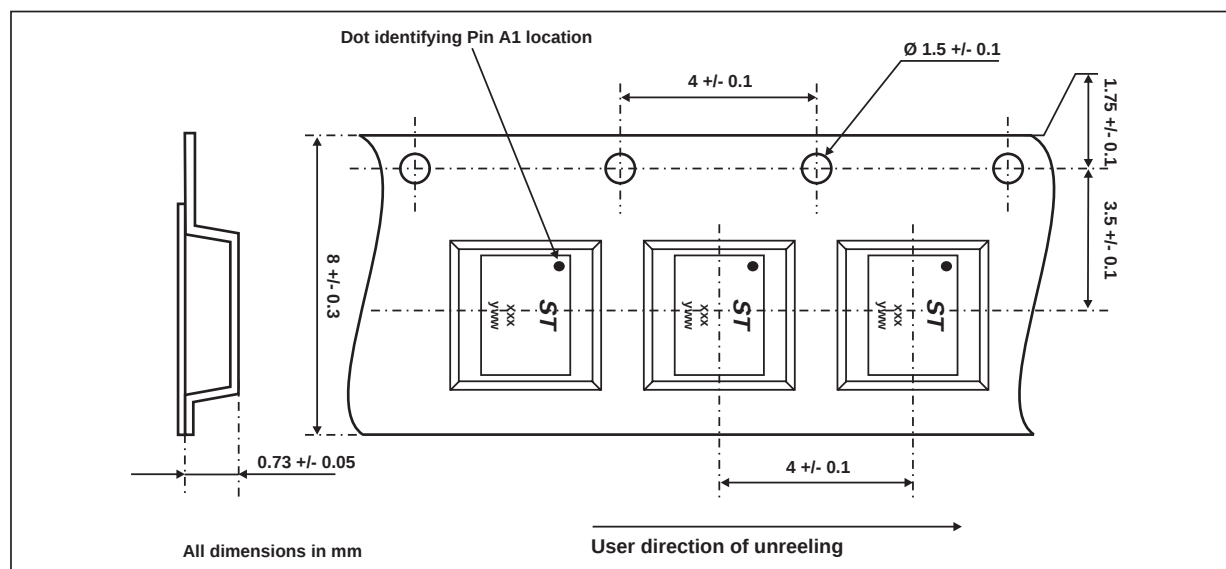
FOOT PRINT RECOMMENDATIONS



MARKING



FLIP-CHIP TAPE AND REEL SPECIFICATION



OTHER INFORMATION

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
EMIF06-10006F1	FTT	Flip-Chip	5.4 mg	5000	Tape & reel

Note: More packing informations are available in the application note AN1235: "Flip-Chip: Package description and recommendations for use"

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